

Features

- Operating voltage: 2.7V~5.5V
- Low power consumption
 - Operation: 25mA max. ($V_{CC}=5V$)
10mA max. ($V_{CC}=3V$)
 - Standby: 30 μ A max. ($V_{CC}=5V$)
10 μ A max. ($V_{CC}=3V$)
- Access time: 120ns max. ($V_{CC}=5V$)
250ns max. ($V_{CC}=3V$)
- 524288×8-bit of mask ROM
- Mask option: chip enable $\overline{CE}/\overline{CE1}/\overline{OE1}$, and output enable $\overline{OE}/\overline{OE/NC}$
- TTL compatible inputs and outputs
- Tristate outputs
- Fully static operation
- 32-pin DIP/SOP/PLCC package

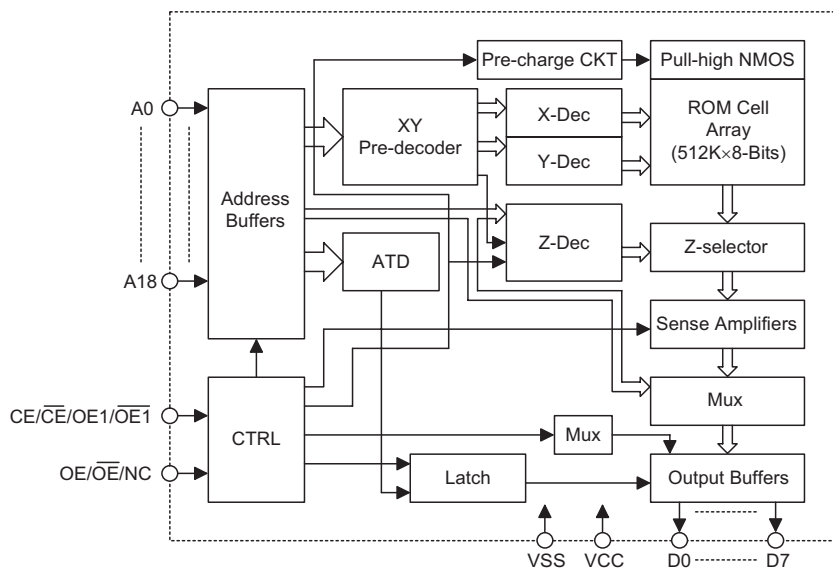
General Description

The HT23C040 is a read-only memory with high performance CMOS storage device whose 4096K of memory is arranged into 524288 word by 8 bits.

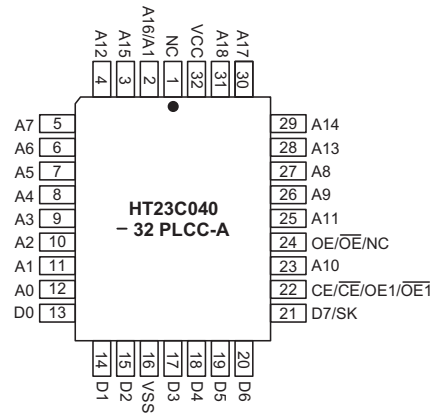
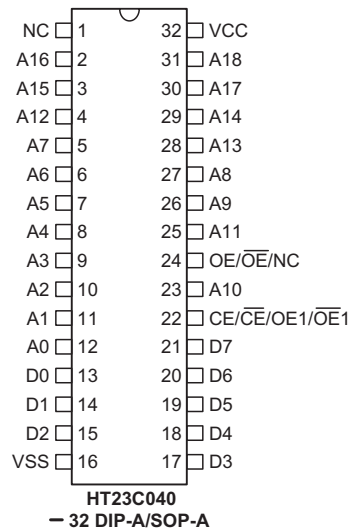
For application flexibility, the chip enable and output enable control pins can be selected as active high or active low. This flexibility not only allows easy interface with most microprocessors, but also eliminates bus conten-

tion in multiple bus microprocessor systems. An additional feature of the HT23C040 is its ability to enter the standby mode whenever the chip enable ($\overline{CE}/\overline{CE1}$) is inactive, thus reducing current consumption to below 30 μ A. The combination of these functions makes the chip suitable for high density low power memory applications.

Block Diagram



Pin Assignment



Pin Description

Pin Name	I/O	Description
NC	—	No connection
A0~A18	I	Address inputs
D0~D7	O	Data outputs
VSS	—	Negative power supply, ground
CE/CE/OE1/OE1	I	Chip enable/Output enable input
OE/OE/NC	I	Output enable input
VCC	—	Positive power supply

Absolute Maximum Ratings

Supply Voltage..... $V_{SS}-0.3V$ to $V_{CC}+6V$ Storage Temperature $-50^{\circ}C$ to $125^{\circ}C$
 Input Voltage..... $V_{SS}-0.3V$ to $V_{CC}+0.3V$ Operating Temperature..... $-40^{\circ}C$ to $85^{\circ}C$

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

D.C. Characteristics
 $T_a = -40^\circ\text{C to } 85^\circ\text{C}$

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
		V _{CC}	Conditions				
Supply Voltage: 4.5V~5.5V							
V _{CC}	Operating Voltage	—	—	4.5	—	5.5	V
I _{CC1}	Operating Current	5V	O/P No load, f=5MHz	—	—	25	mA
V _{IL1}	Input Low Voltage	5V	—	V _{SS}	—	0.8	V
V _{IH1}	Input High Voltage	5V	—	2.2	—	V _{CC}	V
V _{OL1}	Output Low Voltage	5V	I _{OL} =3.2mA	—	—	0.4	V
V _{OH1}	Output High Voltage	5V	I _{OH} =-1mA	2.4	—	V _{CC}	V
I _{LI}	Input Leakage Current	5V	V _{IN} =0 to V _{CC}	—	—	10	μA
I _{LO}	Output Leakage Current	5V	V _{OUT} =0 to V _{CC}	—	—	10	μA
I _{STB1}	Standby Current	5V	CE=V _{IL} , $\overline{\text{CE}}=V_{IH}$	—	—	1.5	mA
I _{STB2}	Standby Current	5V	CE≤0.2V CE≥V _{CC} -0.2V	—	—	30	μA
C _{IN}	Input Capacitance (See note)	—	f=1MHz	—	—	10	pF
C _{OUT}	Output Capacitance (See note)	—	f=1MHz	—	—	10	pF
Supply Voltage: 2.7V~3.3V							
V _{CC}	Operating Voltage	—	—	2.7	—	3.3	V
I _{CC2}	Operating Current	3V	O/P No load, f=5MHz	—	—	10	mA
V _{IL2}	Input Low Voltage	3V	—	V _{SS}	—	0.4	V
V _{IH2}	Input High Voltage	3V	—	1.5	—	V _{CC}	V
V _{OL2}	Output Low Voltage	3V	I _{OL} =2mA	—	—	0.4	V
V _{OH2}	Output High Voltage	3V	I _{OH} =-0.6mA	1.5	—	V _{CC}	V
I _{LI}	Input Leakage Current	3V	V _{IN} =0 to V _{CC}	—	—	10	μA
I _{LO}	Output Leakage Current	3V	V _{OUT} =0 to V _{CC}	—	—	10	μA
C _{IN}	Input Capacitance (See Note)	—	f=1MHz	—	—	10	pF
C _{OUT}	Output Capacitance (See Note)	—	f=1MHz	—	—	10	pF

Note: These parameters are periodically sampled but not 100% tested.

A.C. Characteristics
 $T_a = -40^\circ\text{C to } 85^\circ\text{C}$

Symbol	Parameter	3V±10%		5V±10%		Unit
		Min.	Max.	Min.	Max.	
t _{CYC}	Cycle Time	200	—	120	—	ns
t _{AA}	Address Access Time	—	250	—	120	ns
t _{ACE}	Chip Enable Access Time	—	250	—	120	ns
t _{AOE}	Output Enable Access Time	—	150	—	80	ns
t _{OH}	Output Hold Time	—	—	10	—	ns
t _{OD}	Output Disable Time (See Note)	—	—	—	70	ns
t _{OE}	Output Enable Time (See Note)	—	—	10	—	ns

Note: These parameters are periodically sampled but not 100% tested.

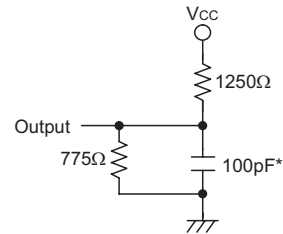
A.C. Test Condition

Output load: see figure right

Input rise and fall time: 10ns

Input pulse levels: 0.4V to 2.4V

Input and output timing reference levels:
 0.8V and 2.0V ($V_{CC}=5V$)
 1.5V ($V_{CC}=3V$)



* Including scope and jig

Output Load Circuit

Functional Description

The HT23C040 has two modes, namely data read mode and standby mode, controlled by $\overline{CE}/\overline{OE1}/\overline{OE1}$ and $\overline{OE}/\overline{OE}/\overline{NC}$ inputs.

• Standby mode

The HT23C040 offers lower current consumption, controlled by the chip enable input ($\overline{CE}/\overline{CE}$). When a low/high level is applied to the $\overline{CE}/\overline{CE}$ input regardless of the output enable ($\overline{OE}/\overline{OE}/\overline{NC}$) states the chip will enter the standby mode.

• Data read mode

When both the chip enable ($\overline{CE}/\overline{CE}/\overline{OE1}/\overline{OE1}$) and the output enable ($\overline{OE}/\overline{OE}/\overline{NC}$) are active, the chip is in data read mode. Otherwise, active $\overline{CE}/\overline{CE}$ and inactive $\overline{OE}/\overline{OE}/\overline{NC}$ result in deselect mode. The output will remain in Hi-Z state.

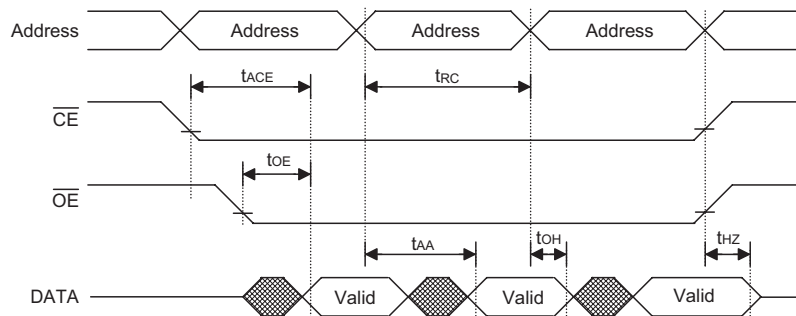
Operation Truth Table

Mode	$\overline{CE}/\overline{CE}$	$\overline{OE}/\overline{OE}$	A0~A18	D0~D7
Read	H/L	H/L	Valid	Data Out
Deselect	H/L	L/H	X	High Z
Standby	L/H	X	X	High Z

Note: H= V_{IH} , L= V_{IL} , X= V_{IH} or V_{IL}

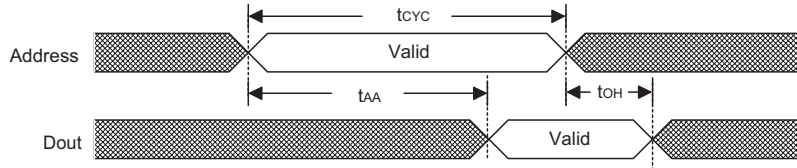
Timing Diagrams

Random Read

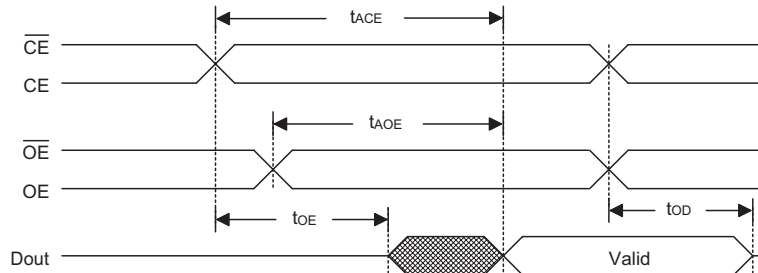


Note: \overline{CE} , \overline{OE} are enable

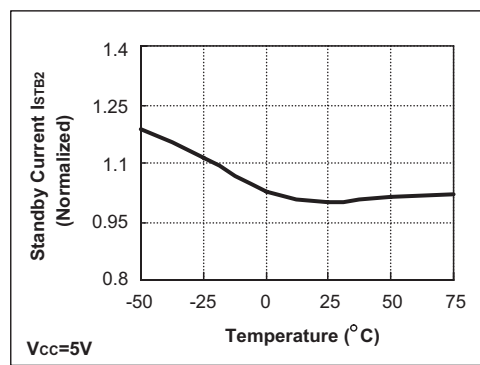
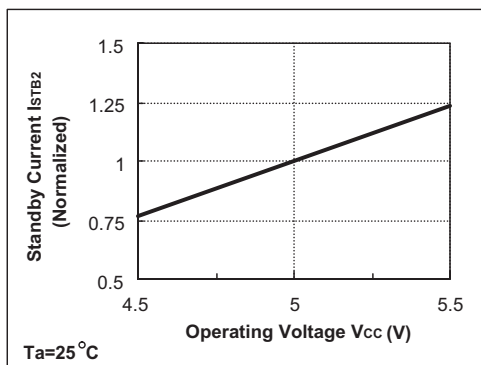
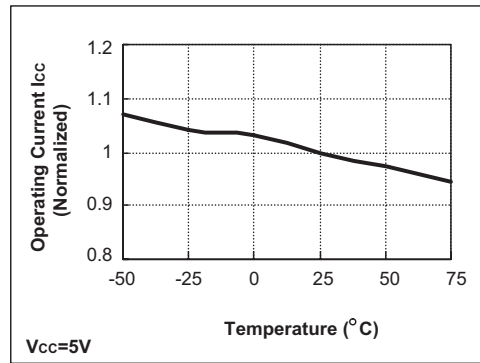
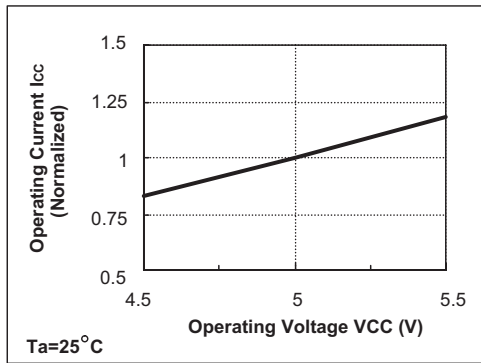
Propagation Delay Due to Address ($\overline{CE}/\overline{CE1}/\overline{OE1}$ and $\overline{OE}/\overline{OE}$ are Active)

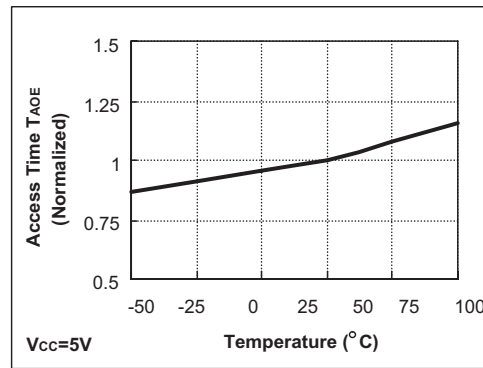
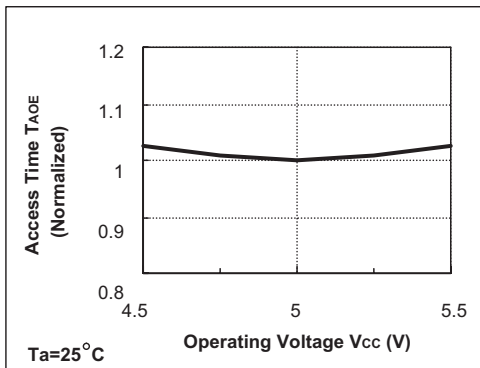
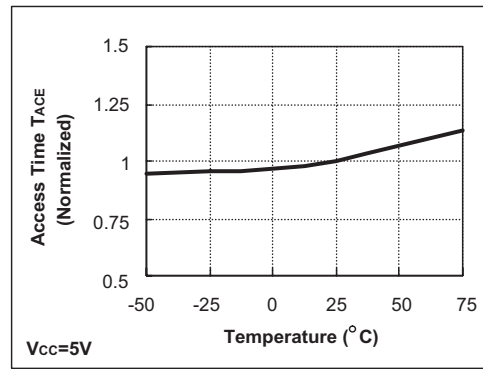
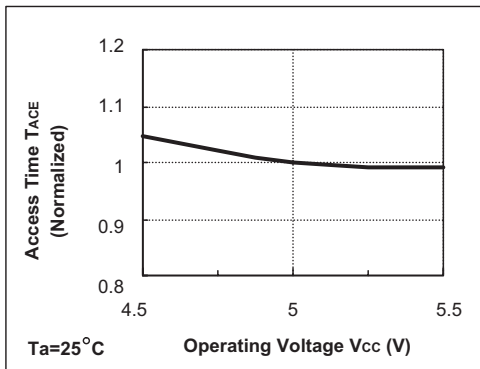
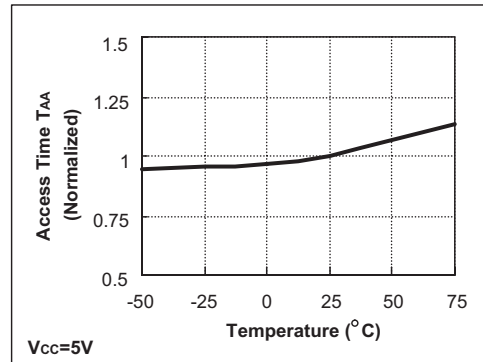
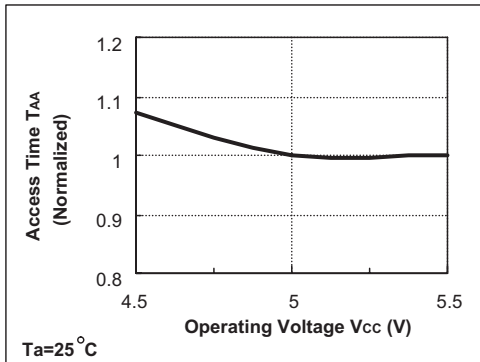


Propagation Delay Due to Chip and Output Enable (Address Valid)



Characteristic Curves





HT23C040 Mask ROM Ordering Sheet

Custom: _____

Input Medium:

EPROM DISK File (Mail Address: romfile@holtek.com.tw) OTHER _____

User No.	Type/Ref. Name	Q'ty	Check Sum	Memory Address	
				Start	End

Control Pin and Package Form Option:

(a) 32 Pin Type Pin 22: _____ (1) CE (2) \overline{CE} (3) OE1 (4) $\overline{OE1}$
Pin 24: _____ (1) OE (2) \overline{OE} (3) NC
(b) Package Form: _____ (1) Chip Form (2) 32 DIP (3) 32 SOP

Companion User No. _____

Package Marking : _____

Delivery Date : _____ Q'ty: _____

CUSTOM CONFIRMED BY:

(NAME, DATE, POSITION & CO. CHOP)

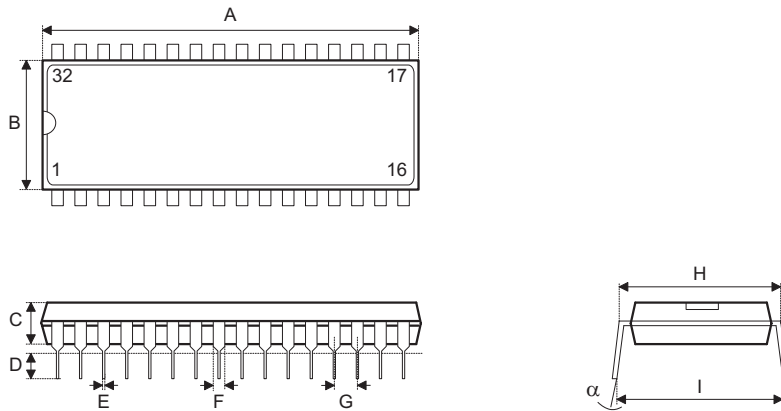
HOLTEK CONFIRMED BY:

(SALES)

(SALES MANAGER)

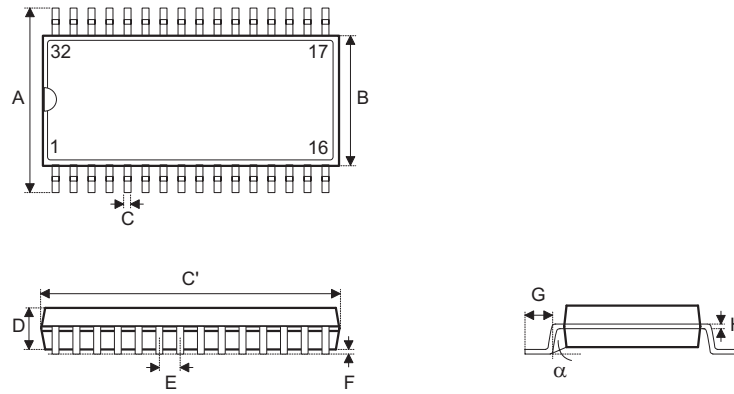
Package Information

32-pin DIP (600mil) Outline Dimensions



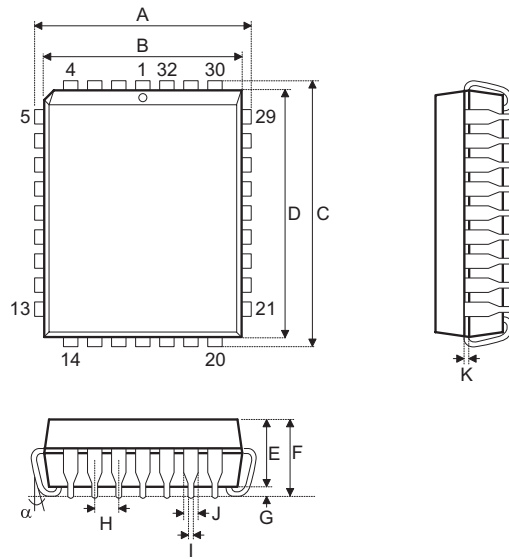
Symbol	Dimensions in mil		
	Min.	Nom.	Max.
A	1635	—	1665
B	535	—	555
C	145	—	155
D	125	—	145
E	16	—	20
F	50	—	70
G	—	100	—
H	595	—	615
I	635	—	670
α	0°	—	15°

32-pin SOP (450mil) Outline Dimensions



Symbol	Dimensions in mil		
	Min.	Nom.	Max.
A	543	—	557
B	440	—	450
C	14	—	20
C'	—	—	817
D	100	—	112
E	—	50	—
F	4	—	—
G	32	—	38
H	4	—	12
α	0°	—	10°

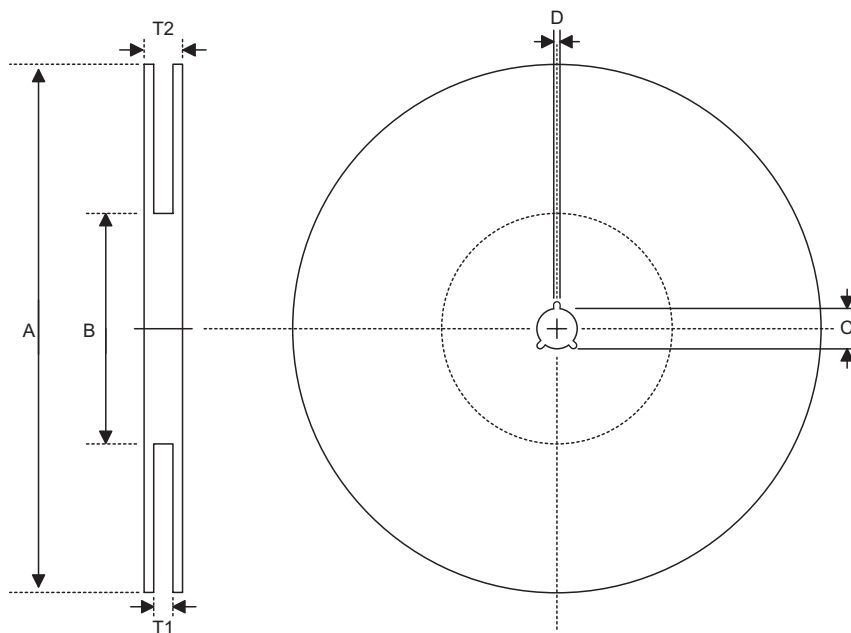
32-pin PLCC Outline Dimensions



Symbol	Dimensions in mil		
	Min.	Nom.	Max.
A	485	—	495
B	445	—	455
C	585	—	595
D	545	—	555
E	105	—	115
F	—	—	140
G	15	—	—
H	—	50	—
I	16	—	22
J	24	—	32
K	8	—	12
α	0°	—	10°

Product Tape and Reel Specifications

Reel Dimensions



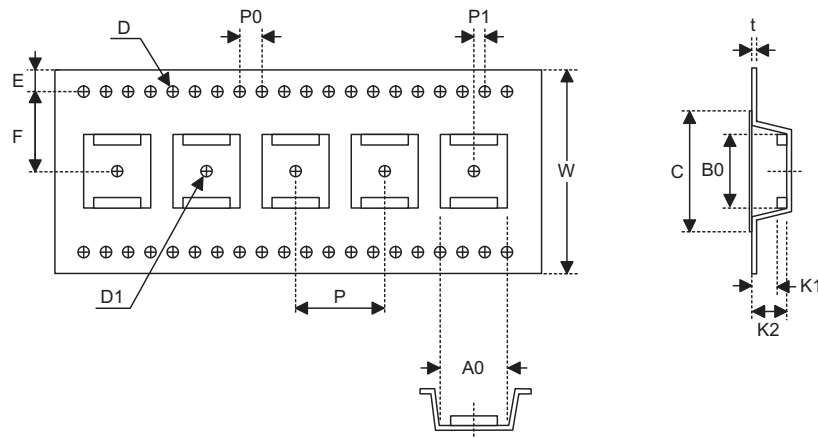
SOP 32W

Symbol	Description	Dimensions in mm
A	Reel Outer Diameter	330±1.0
B	Reel Inner Diameter	100±0.1
C	Spindle Hole Diameter	13.0+0.5 -0.2
D	Key Slit Width	2.0±0.5
T1	Space Between Flange	32.8+0.3 -0.2
T2	Reel Thickness	38.2+0.2

PLCC 32

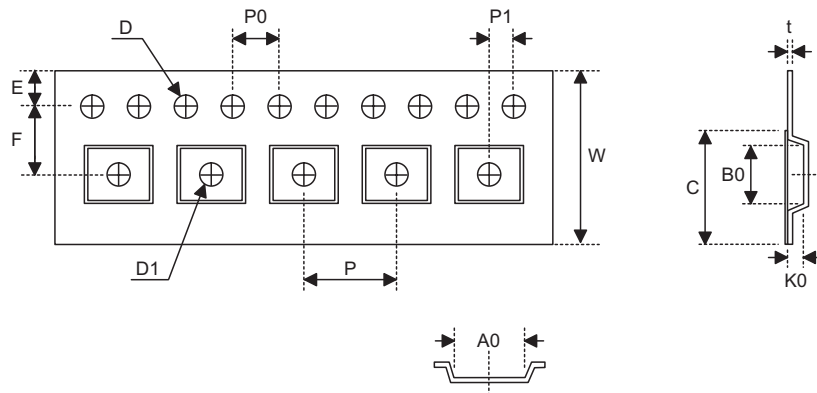
Symbol	Description	Dimensions in mm
A	Reel Outer Diameter	330±1.0
B	Reel Inner Diameter	62±1.5
C	Spindle Hole Diameter	13.0+0.5 -0.2
D	Key Slit Width	2.0±0.5
T1	Space Between Flange	24.8+0.3 -0.2
T2	Reel Thickness	30.2±0.2

Carrier Tape Dimensions



SOP 32W

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	32.0+0.3 -0.1
P	Cavity Pitch	16.0±0.1
E	Perforation Position	1.75±0.1
F	Cavity to Perforation (Width Direction)	14.2±0.1
D	Perforation Diameter	1.55+0.1
D1	Cavity Hole Diameter	2.0+0.25
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.0±0.1
A0	Cavity Length	14.7±0.1
B0	Cavity Width	20.9±0.1
K1	Cavity Depth	3.0±0.1
K2	Cavity Depth	3.4±0.1
t	Carrier Tape Thickness	0.35±0.05
C	Cover Tape Width	25.5



PLCC 32

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	24.0±0.3
P	Cavity Pitch	18.0±0.1
E	Perforation Position	1.75±0.1
F	Cavity to Perforation (Width Direction)	11.5±0.1
D	Perforation Diameter	1.5+0.1
D1	Cavity Hole Diameter	1.55+1.0 -0.05
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.0±0.1
A0	Cavity Length	13.1±0.1
B0	Cavity Width	15.5±0.1
K0	Cavity Depth	3.9±0.1
t	Carrier Tape Thickness	0.30±0.05
C	Cover Tape Width	21.3

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